

الجامعة الإسلامية العالمية ماليزيا
INTERNATIONAL ISLAMIC UNIVERSITY MALAYSIA
يُونَيْتِي سَلَامٌ، أَنْتَ رَابِعِيَا مَلِيْسِيَا

KULLIYAH OF ENGINEERING

**END OF SEMESTER EXAMINATION
SEMESTER I, 2017/2018 SESSION**

Programme	: Engineering	Level of Study	: UG 2
Time	: 9:00 am -12:00 pm	Date	: 02/01/2018
Duration	: 3 Hrs		
Course Code	: EECE 2313/ECE 2133	Section(s)	: 1-3
Course Title	: Electronic Circuits		

This Question Paper Consists of **6 (Six)** Printed Pages (Including Cover Page) with **5 (Five)** Questions.

INSTRUCTION(S) TO CANDIDATES

DO NOT OPEN UNTIL YOU ARE ASKED TO DO SO

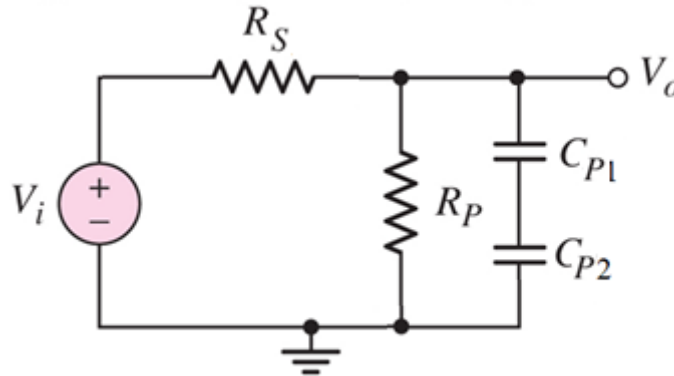
- Total mark of this examination is **100**.
- This examination is worth **50 %** of the total course assessment.
- Answer **ALL QUESTIONS**.
- Only approved calculator with 'KoE approved' sticker is allowed (non-programmable and non-graphical).
- Marks assigned to each problem are listed in the margins.

Any form of cheating or attempt to cheat is a serious offence which may lead to dismissal.

***All electronics gadgets are prohibited in the exam hall / venue.
(e.g. mobile / smart phones, smart watches, and smart glasses)***

Q.1 [20 marks]

- (a) Consider the circuit shown in **Fig. 1(a)**, derive the expression (step by step) for the voltage transfer function, $T(s) = v_o(s)/v_i(s)$. Find the corner frequency of the circuit if $C_{P1} = 30$ pF, $C_{P2} = 60$ pF, $R_S = 30$ k Ω and $R_P = 60$ k Ω . (8 marks)

**Fig. 1(a)**

- (b) Draw the Bode plot (magnitude and phase) of the following transfer function. (8 marks)

$$T(s) = 10^6 \frac{s(s + 50)}{(s + 500)(s + 100)}$$

- (c) Determine the magnitude and phase of the transfer function from the plots drawn for **Q1(b)** at frequency $\omega = 300$ radian/sec. (4 marks)

Q.2 [20 marks]

- (a) The common emitter amplifier as shown in **Fig. 2(a)** with the following circuit component values, $R_s = 0.5$ k Ω , $R_1 = 234$ k Ω , $R_2 = 166$ k Ω , $R_E = 1$ k Ω , $R_C = 5$ k Ω , $R_L = 20$ k Ω . The BJT has small-signal hybrid- π parameters, $g_m = 40$ mA/V, $r_\pi = 3$ k Ω and $r_o = \infty$.

Design the amplifier circuit that operates at lower corner frequency, $f_L = 300$ Hz and the bandwidth of the amplifier, $BW = 500$ kHz. Determine the maximum gain of the designed amplifier in dB. (10 Marks)

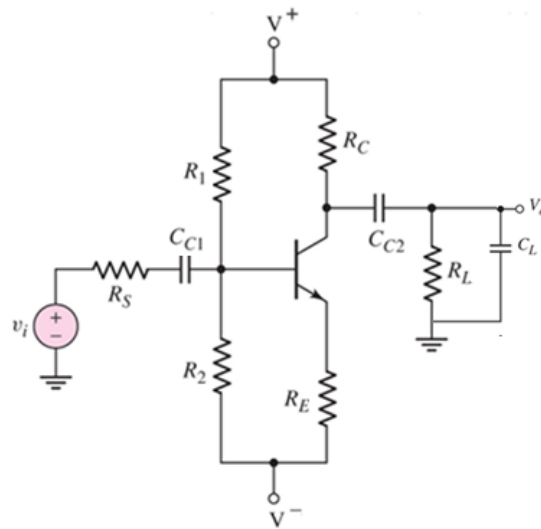


Fig. 2(a)

(b) Draw the simplified small-signal high-frequency equivalent circuit of Fig. 2(b). (2 marks)

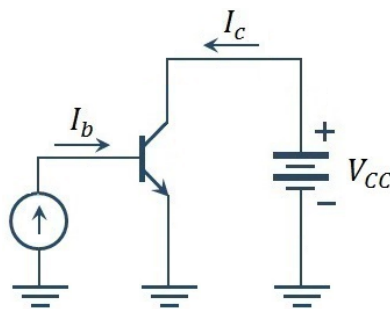


Fig. 2(b)

(c) Determine the transistor short-circuit beta frequency, f_β and cutoff frequency, f_T using the simplified small-signal high-frequency equivalent circuit of Fig. 2(b). (8 marks)

Q.3 [20 marks]

(a) The three transistor current source as shown in Fig. 3(a) has a finite β and infinite early voltage V_A . Derive step by step the expression for I_O in terms of I_{REF} and β . (10 marks)

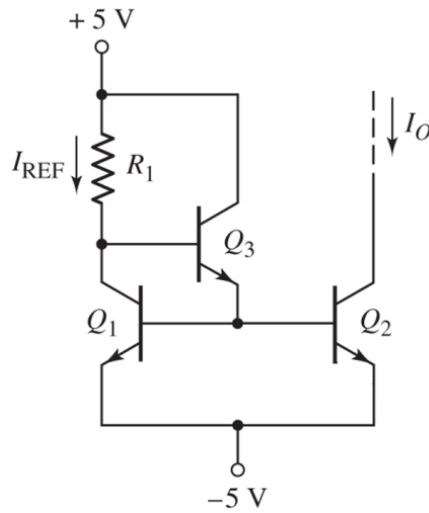
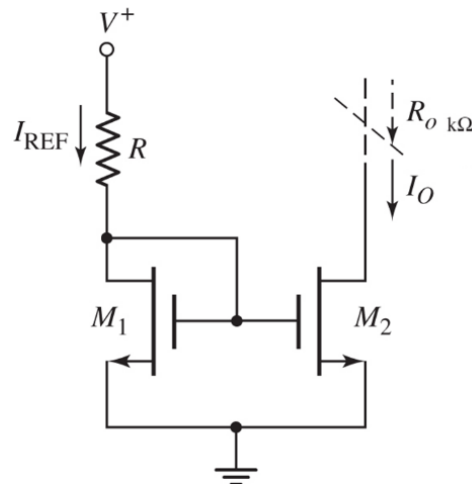


Fig. 3(a)

- (b) Design a three transistor current source as shown in Fig. 3(a) such that $I_O = 5$ mA. What is the value of I_{REF} ? The transistor parameters are: $V_{BE(on)} = 0.7$ V, $\beta = 100$ and $V_A = \infty$. (4 marks)
- (c) Draw the small signal equivalent circuit diagram of the current source shown in Fig. 3(a). (2 marks)
- (d) Design a MOSFET current source as shown in Fig. 3(b) such that $I_{REF} = 20$ mA, $I_o = 50$ mA, and $V_{DS2(sat)} = 0.2$ V. The biasing voltage, $V^+ = 12$ V. The transistors are available with parameters: $k'_n = 50 \mu A/V^2$, $V_{TN} = 0.4$ V and $\lambda = 0$. (4 marks)



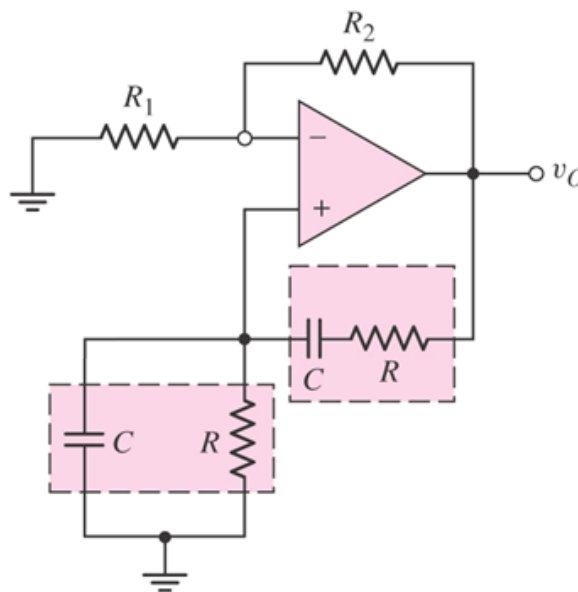
(a) Fig. 3(b)

Q.4 [20 marks]

- (a) What are the merits and demerits of the negative feedback amplifier? (3 marks)
- (b) Prove that gain sensitivity of an amplifier is improved with negative feedback. (4 marks)
- (c) The open loop gain of a voltage amplifier is changed from 1000 to 850 due to temperature effects. Design a negative feedback system to improve the gain stability 1.5% by determining the feedback factor β . (3 marks)
- (d) Draw the block diagram and small signal equivalent circuit diagram of a shunt-shunt ideal feedback amplifier. Analyze step by step the feedback amplifier to find the expression of the closed loop gain, A_f , the input resistance, R_{if} and the output resistance, R_{of} in terms of open-loop amplifier gain, A and feedback amplifier gain, β . (10 marks)

Q.5 [20 marks]

- (a) What are the conditions for oscillation? (2 marks)
- (b) A wine bridge oscillator circuit is shown in **Fig. 5**. Derive the transfer function of the feedback network and derive the frequency of oscillation, f_o . Find the minimum amplifier gain for sustained oscillations. (12 marks)

**Fig. 5**

- (c) Design a wine bridge oscillator for generating 20 kHz. Assume that the capacitor value is 0.8nF. (4 marks)

USEFUL FORMULA

BJT	MOSFET
$i_C = I_S e^{v_{BE}/V_T} \cdot \left(1 + \frac{v_{CE}}{V_A}\right)$ $g_m = \frac{I_{CQ}}{V_T}$ $r_\pi = \frac{\beta V_T}{I_{CQ}}$ $r_o = \frac{V_A}{I_{CQ}}$ $V_T = 26 \text{ mV}$ $V_{BE(on)} = 0.7 \text{ V}$	$I_D = \frac{1}{2} k'_n \left(\frac{W}{L}\right) (V_{GS} - V_T)^2 (1 + \lambda V_{DS})$ $g_m = 2\sqrt{K_n I_{DQ}}$ $r_o = \frac{1}{\lambda I_{DQ}}$ $K_n = \frac{k'_n}{2} \left(\frac{W}{L}\right)$

END OF PAPER